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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

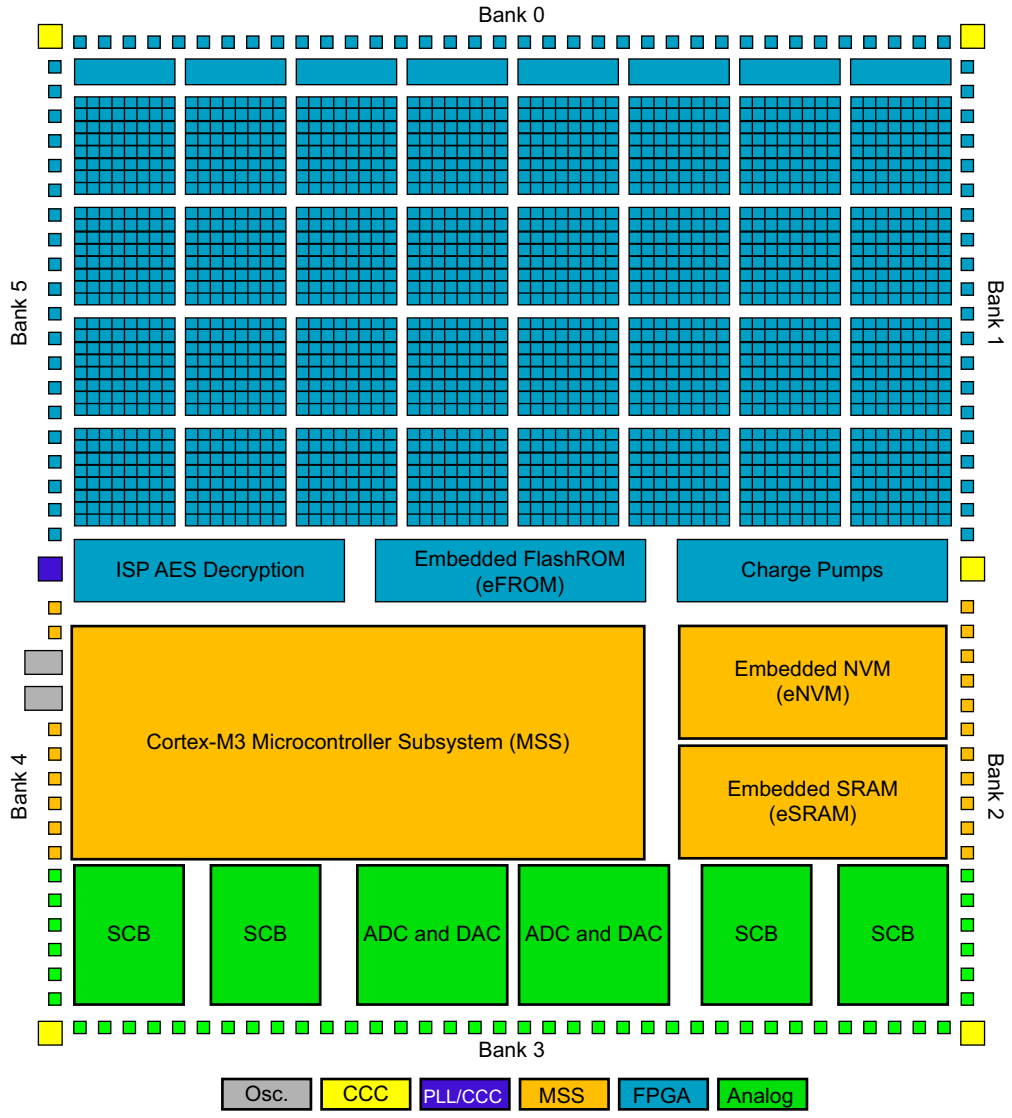
Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details	
Product Status	Obsolete
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	128KB
RAM Size	16KB
Peripherals	DMA, POR, WDT
Connectivity	EBI/EMI, I²C, SPI, UART/USART
Speed	80MHz
Primary Attributes	ProASIC®3 FPGA, 60K Gates, 1536D-Flip-Flops
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	288-TFBGA, CSPBGA
Supplier Device Package	288-CSP (11x11)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a2f060m3e-cs288

SmartFusion cSoC System Architecture



Note: Architecture for A2F200

Table 2-3 • Recommended Operating Conditions[5,6]

Symbol	Parameter[1]		Commercial	Industrial	Units
T_J	Junction temperature		0 to +85	–40 to +100	°C
VCC [2]	1.5 V DC core supply voltage		1.425 to 1.575	1.425 to 1.575	V
VJTAG	JTAG DC voltage		1.425 to 3.6	1.425 to 3.6	V
VPP	Programming voltage	Programming mode[3]	3.15 to 3.45	3.15 to 3.45	V
		Operation[4]	0 to 3.6	0 to 3.6	V
VCCPLLx	Analog power supply (PLL)		1.425 to 1.575	1.425 to 1.575	V
VCCFPGAIOBx/ VCCMSSIOBx[5]	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	LVDS differential I/O		2.375 to 2.625	2.375 to 2.625	V
	LVPECL differential I/O		3.0 to 3.6	3.0 to 3.6	V
VCC33A[6]	Analog clean 3.3 V supply to the analog circuitry		3.15 to 3.45	3.15 to 3.45	V
VCC33ADCx[6]	Analog 3.3 V supply to ADC		3.15 to 3.45	3.15 to 3.45	V
VCC33AP[6]	Analog clean 3.3 V supply to the charge pump		3.15 to 3.45	3.15 to 3.45	V
VCC33SDDx[6]	Analog 3.3 V supply to sigma-delta DAC		3.15 to 3.45	3.15 to 3.45	V
VAREFx	Voltage reference for ADC		2.527 to 3.3	2.527 to 3.3	V
VCCRCOSC	Analog supply to the integrated RC oscillator		3.15 to 3.45	3.15 to 3.45	V
VDDBAT	External battery supply		2.7 to 3.63	2.7 to 3.63	V
VCCMAINXTAL[6]	Analog supply to the main crystal oscillator		3.15 to 3.45	3.15 to 3.45	V
VCCLPXTAL[6]	Analog supply to the low power 32 KHz crystal oscillator		3.15 to 3.45	3.15 to 3.45	V
VCCENVM	Embedded nonvolatile memory supply		1.425 to 1.575	1.425 to 1.575	V
VCCESRAM	Embedded SRAM supply		1.425 to 1.575	1.425 to 1.575	V
VCC15A[2]	Analog 1.5 V supply to the analog circuitry		1.425 to 1.575	1.425 to 1.575	V
VCC15ADCx[2]	Analog 1.5 V supply to the ADC		1.425 to 1.575	1.425 to 1.575	V

Notes:

1. *All parameters representing voltages are measured with respect to GND unless otherwise specified.*
2. *The following 1.5 V supplies should be connected together while following proper noise filtering practices: VCC, VCC15A, and VCC15ADCx.*
3. *The Programming temperature range supported is $T_{ambient}$ = 0°C to 85°C.*
4. *VPP can be left floating during operation (not programming mode).*
5. *The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-19 on page 2-23. VCCxxxxIOBx should be at the same voltage within a given I/O bank.*
6. *The following 3.3 V supplies should be connected together while following proper noise filtering practices: VCC33A, VCC33ADCx, VCC33AP, VCC33SDDx, VCCMAINXTAL, and VCCLPXTAL.*

Table 2-4 • FPGA and Embedded Flash Programming, Storage and Operating Limits

Product Grade	Storage Temperature	Element	Grade Programming Cycles	Retention
Commercial	Min. T_J = 0°C Max. T_J = 85°C	FPGA/FlashROM	500	20 years
		Embedded Flash	< 1,000	20 years
			< 10,000	10 years
			< 15,000	5 years
Industrial	Min. T_J = –40°C Max. T_J = 100°C	FPGA/FlashROM	500	20 years
		Embedded Flash	< 1,000	20 years
			< 10,000	10 years
			< 15,000	5 years

Table 2-5 • Overshoot and Undershoot Limits [1]

VCCxxxxIOBx	Average VCCxxxxIOBx–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle[2]	Maximum Overshoot/ Undershoot[2]
2.7 V or less	10%	1.4 V
	5%	1.49 V
3 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

Notes:

1. *Based on reliability requirements at 85°C.*
2. *The duration is allowed at one out of six clock cycles. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.*
3. *This table does not provide PCI overshoot/undershoot limits.*

Power Supply Sequencing Requirement

SmartFusion cSoCs have an on-chip 1.5 V regulator, but usage of an external 1.5 V supply is also allowed while the on-chip regulator is disabled. In that case, the 3.3 V supplies (VCC33A, etc.) should be powered before 1.5 V (VCC, etc.) supplies. The 1.5 V supplies should be enabled only after 3.3 V supplies reach a value higher than 2.7 V.

I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every SmartFusion cSoC. These circuits ensure easy transition from the powered-off state to the powered-up state of the device. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 2-1 on page 2-6.

There are five regions to consider during power-up.

SmartFusion I/Os are activated only if ALL of the following three conditions are met:

1. VCC and VCCxxxxIOBx are above the minimum specified trip points (Figure 2-1 on page 2-6).
2. VCCxxxxIOBx > VCC – 0.75 V (typical)
3. Chip is in the SoC Mode.

Power Calculation Methodology

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in the Libero SoC software.

The power calculation methodology described below uses the following variables:

- The number of PLLs/CCCs as well as the number and the frequency of each output clock generated
- The number of combinatorial and sequential cells used in the design
- The internal clock frequencies
- The number and the standard of I/O pins used in the design
- The number of RAM blocks used in the design
- The number of eNVM blocks used in the design
- The analog block used in the design, including the temperature monitor, current monitor, ABPS, sigma-delta DAC, comparator, low power crystal oscillator, RC oscillator and the main crystal oscillator
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in Table 2-17 on page 2-18.
- Enable rates of output buffers—guidelines are provided for typical applications in Table 2-18 on page 2-18.
- Read rate and write rate to the memory—guidelines are provided for typical applications in Table 2-18 on page 2-18.
- Read rate to the eNVM blocks

The calculation should be repeated for each clock domain defined in the design.

Methodology

Total Power Consumption—P_{TOTAL}

SoC Mode, Standby Mode, and Time Keeping Mode.

$P_{TOTAL} = P_{STAT} + P_{DYN}$

P_{STAT} is the total static power consumption.

P_{DYN} is the total dynamic power consumption.

Total Static Power Consumption—P_{STAT}

SoC Mode

$P_{STAT} = P_{DC1} + (N_{INPUTS} * P_{DC7}) + (N_{OUTPUTS} * P_{DC8}) + (N_{PLLS} * P_{DC9})$

N_{INPUTS} is the number of I/O input buffers used in the design.

$N_{OUTPUTS}$ is the number of I/O output buffers used in the design.

N_{PLLS} is the number of PLLs available in the device.

Standby Mode

$P_{STAT} = P_{DC2}$

Time Keeping Mode

$P_{STAT} = P_{DC3}$

Total Dynamic Power Consumption—P_{DYN}

SoC Mode

$P_{DYN} = P_{CLOCK} + P_{S\text{-}CELL} + P_{C\text{-}CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL} + P_{eNVM} + P_{XTL\text{-}OSC} + P_{RC\text{-}OSC} + P_{AB} + P_{LPXTAL\text{-}OSC} + P_{MSS}$

Standby Mode

$P_{DYN} = P_{RC\text{-}OSC} + P_{LPXTAL\text{-}OSC}$

Time Keeping Mode

$P_{DYN} = P_{LPXTAL\text{-}OSC}$

Global Clock Dynamic Contribution—P_{CLOCK}

SoC Mode

$P_{CLOCK} = (P_{AC1} + N_{SPINE} * P_{AC2} + N_{ROW} * PAC3 + N_{S\text{-}CELL} * P_{AC4}) * F_{CLK}$

N_{SPINE} is the number of global spines used in the user design—guidelines are provided in the "Device Architecture" chapter of the *SmartFusion FPGA Fabric User's Guide*.

N_{ROW} is the number of VersaTile rows used in the design—guidelines are provided in the "Device Architecture" chapter of the *SmartFusion FPGA Fabric User's Guide*.

F_{CLK} is the global clock signal frequency.

$N_{S\text{-}CELL}$ is the number of VersaTiles used as sequential modules in the design.

Standby Mode and Time Keeping Mode

$P_{CLOCK} = 0$ W

Sequential Cells Dynamic Contribution—$P_{S\text{-}CELL}$

SoC Mode

$P_{S\text{-}CELL} = N_{S\text{-}CELL} * (P_{AC5} + (\alpha_1 / 2) * P_{AC6}) * F_{CLK}$

$N_{S\text{-}CELL}$ is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

α_1 is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-17 on page 2-18.

F_{CLK} is the global clock signal frequency.

Standby Mode and Time Keeping Mode

$P_{S\text{-}CELL} = 0$ W

Combinatorial Cells Dynamic Contribution—$P_{C\text{-}CELL}$

SoC Mode

$P_{C\text{-}CELL} = N_{C\text{-}CELL} * (\alpha_1 / 2) * P_{AC7} * F_{CLK}$

$N_{C\text{-}CELL}$ is the number of VersaTiles used as combinatorial modules in the design.

α_1 is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-17 on page 2-18.

F_{CLK} is the global clock signal frequency.

Standby Mode and Time Keeping Mode

$P_{C\text{-}CELL} = 0$ W

Routing Net Dynamic Contribution—P_{NET}

SoC Mode

$P_{NET} = (N_{S\text{-}CELL} + N_{C\text{-}CELL}) * (\alpha_1 / 2) * P_{AC8} * F_{CLK}$

$N_{S\text{-}CELL}$ is the number VersaTiles used as sequential modules in the design.

$N_{C\text{-}CELL}$ is the number of VersaTiles used as combinatorial modules in the design.

α_1 is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-17 on page 2-18.

F_{CLK} is the frequency of the clock driving the logic including these nets.

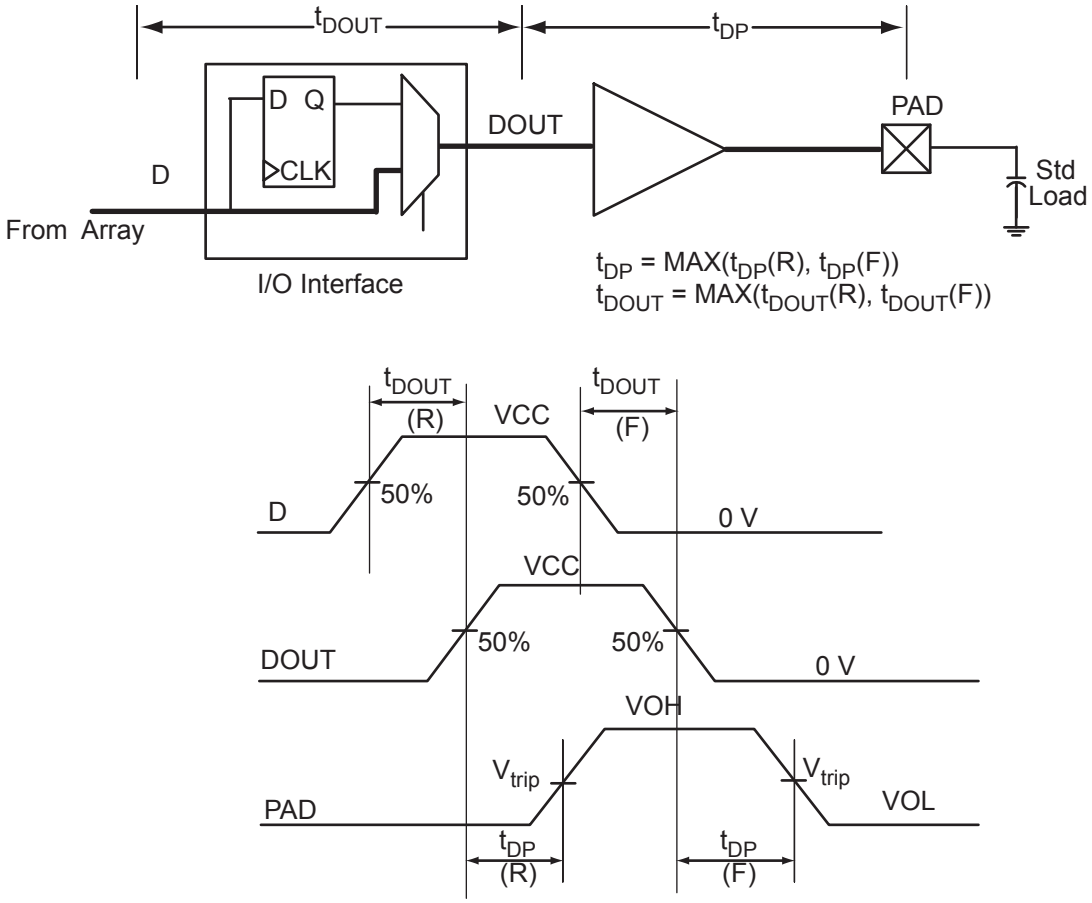


Figure 2-4 • **Output Buffer Model and Delays (example)**

Overview of I/O Performance

Summary of I/O DC Input and Output Levels – Default I/O Software Settings

Table 2-19 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial Conditions—Software Default Settings Applicable to FPGA I/O Banks

I/O Standard	Drive Strgth.	Slew Rate	VIL		VIH		VOL	VOH	I_{OL}[1]	I_{OH}[1]
			Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	High	–0.3	0.8	2	3.6	0.4	2.4	12	12
2.5 V LVCMOS	12 mA	High	–0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVCMOS	12 mA	High	–0.3	0.35 * VCCxxxxIOBx	0.65* VCCxxxxIOBx	3.6	0.45	VCCxxxxIOBx – 0.45	12	12
1.5 V LVCMOS	12 mA	High	–0.3	0.35 * VCCxxxxIOBx	0.65* VCCxxxxIOBx	3.6	0.25 * VCCxxxxIOBx	0.75* VCCxxxxIOBx	12	12
3.3 V PCI	Per PCI specifications									
3.3 V PCI-X	Per PCI-X specifications									

Notes:

1. *Currents are measured at 85°C junction temperature.*
2. *Output slew rate can be extracted by the IBIS Models.*

Table 2-20 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial Conditions—Software Default Settings Applicable to MSS I/O Banks

I/O Standard	Drive Strgth.	Slew Rate	VIL		VIH		VOL	VOH	I_{OL}[1]	I_{OH}[1]
			Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	High	–0.3	0.8	2	3.6	0.4	2.4	8	8
2.5 V LVCMOS	8 mA	High	–0.3	0.7	1.7	3.6	0.7	1.7	8	8
1.8 V LVCMOS	4 mA	High	–0.3	0.35* VCCxxxxIOBx	0.65* VCCxxxxIOBx	3.6	0.45	VCCxxxxIOBx – 0.45	4	4
1.5 V LVCMOS	2 mA	High	–0.3	0.35* VCCxxxxIOBx	0.65* VCCxxxxIOBx	3.6	0.25* VCCxxxxIOBx	0.75* VCCxxxxIOBx	2	2

Notes:

1. *Currents are measured at 85°C junction temperature.*
2. *Output slew rate can be extracted by the IBIS Models.*

Table 2-24 • Summary of I/O Timing Characteristics—Software Default Settings –1 Speed Grade, Worst Commercial-Case Conditions: T_J = 85°C, Worst Case VCC = 1.425 V, Worst-Case VCCxxxxIOBx (per standard) Applicable to FPGA I/O Banks, Assigned to EMC I/O Pins

I/O Standard	Drive Strength	Slew Rate	Capacitive Load (pF)	External Resistor (Ω)	t_{DOUT} (ns)	t_{DP} (ns)	t_{DIN} (ns)	t_{PY} (ns)	t_{EOUT} (ns)	t_{ZL} (ns)	t_{ZH} (ns)	t_{LZ} (ns)	t_{HZ} (ns)	t_{ZLS} (ns)	t_{ZHS} (ns)	Units
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	High	35	–	0.50	2.81	0.03	0.81	0.32	2.86	2.23	2.55	2.82	4.58	3.94	ns
2.5 V LVCMOS	12 mA	High	35	–	0.50	2.73	0.03	1.03	0.32	2.88	2.69	2.62	2.70	4.60	4.41	ns
1.8 V LVCMOS	12 mA	High	35	–	0.50	2.81	0.03	0.95	0.32	2.87	2.38	2.92	3.18	4.58	4.10	ns
1.5 V LVCMOS	12 mA	High	35	–	0.50	3.24	0.03	1.12	0.32	3.30	2.79	3.10	3.27	5.02	4.50	ns
3.3 V PCI	Per PCI spec	High	10	25[1]	0.50	2.11	0.03	0.68	0.32	2.15	1.57	2.55	2.82	3.87	3.28	ns
3.3 V PCI-X	Per PCI-X spec	High	10	25[1]	0.50	2.11	0.03	0.64	0.32	2.15	1.57	2.55	2.82	3.87	3.28	ns
LVDS	24 mA	High	–	–	0.50	1.53	0.03	1.55	–	–	–	–	–	–	–	ns
LVPECL	24 mA	High	–	–	0.50	1.46	0.03	1.46	–	–	–	–	–	–	–	ns

Notes:

1. *Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-10 on page 2-39 for connectivity. This resistor is not required during normal operation.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.*

Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings –1 Speed Grade, Worst Commercial-Case Conditions: T_J = 85°C, Worst Case VCC = 1.425 V, Worst-Case VCCxxxxIOBx (per standard) Applicable to MSS I/O Banks

I/O Standard	Drive Strength	Slew Rate	Capacitive Load (pF)	External Resistor	t_{DOUT} (ns)	t_{DP} (ns)	t_{DIN} (ns)	t_{PY} (ns)	t_{PYS} (ns)	t_{EOUT} (ns)	t_{ZL} (ns)	t_{ZH} (ns)	t_{LZ} (ns)	t_{HZ} (ns)	Units
3.3 V LVTTL / 3.3 V LVCMOS	8 mA	High	10	–	0.18	1.92	0.07	0.78	1.09	0.18	1.96	1.55	1.83	2.04	ns
2.5 V LVCMOS	8 mA	High	10	–	0.18	1.96	0.07	0.99	1.16	0.18	2.00	1.82	1.82	1.93	ns
1.8 V LVCMOS	4 mA	High	10	–	0.18	2.31	0.07	0.91	1.37	0.18	2.35	2.27	1.84	1.87	ns
1.5 V LVCMOS	2 mA	High	10	–	0.18	2.70	0.07	1.07	1.55	0.18	2.75	2.67	1.87	1.85	ns

Notes:

1. *Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-10 on page 2-39 for connectivity. This resistor is not required during normal operation.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.*

Table 2-63 • LVDS Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Typ.	Max.	Units
VCCFPGAIOBx	Supply voltage	2.375	2.5	2.625	V
VOL	Output low voltage	0.9	1.075	1.25	V
VOH	Output high voltage	1.25	1.425	1.6	V
I_{OL}[1]	Output lower current	0.65	0.91	1.16	mA
I_{OH}[1]	Output high current	0.65	0.91	1.16	mA
VI	Input voltage	0		2.925	V
I_{IH}[2]	Input high leakage current			15	µA
I_{IL}[2]	Input low leakage current			15	µA
V_{ODIFF}	Differential output voltage	250	350	450	mV
V_{OCM}	Output common mode voltage	1.125	1.25	1.375	V
V_{ICM}	Input common mode voltage	0.05	1.25	2.35	V
V_{IDIFF}	Input differential voltage	100	350		mV

Notes:

1. *I_{OL}/I_{OH} defined by V_{ODIFF}/(resistor network).*
2. *Currents are measured at 85°C junction temperature.*

Table 2-64 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V_{REF} (typ.) (V)
1.075	1.325	Cross point	–

* *Measuring point = V_{trip}. See Table 2-22 on page 2-24 for a complete table of trip points.*

Timing Characteristics

Table 2-65 • LVDS
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCFPGAIOBx = 2.3 V
Applicable to FPGA I/O Banks, I/O Assigned to EMC I/O Pins

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	Units
Std.	0.60	1.83	0.04	1.87	ns
–1	0.50	1.53	0.03	1.55	ns

Notes:

1. *For the derating values at specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.*
2. *The above mentioned timing parameters correspond to 24mA drive strength.*

Timing Waveforms

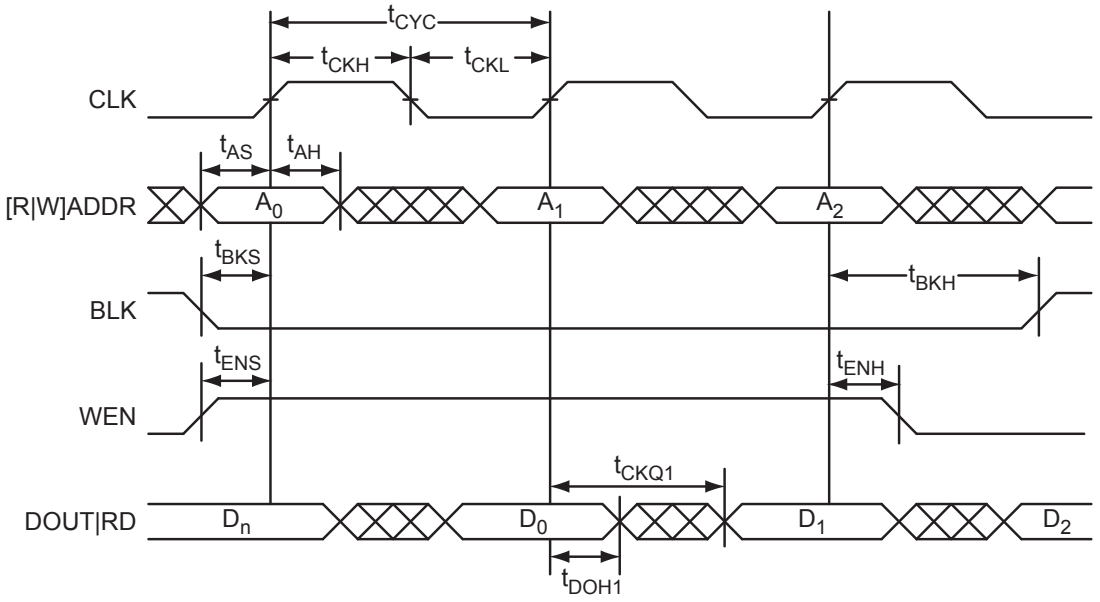


Figure 2-30 • **RAM Read for Pass-Through Output. Applicable to both RAM4K9 and RAM512x18**.

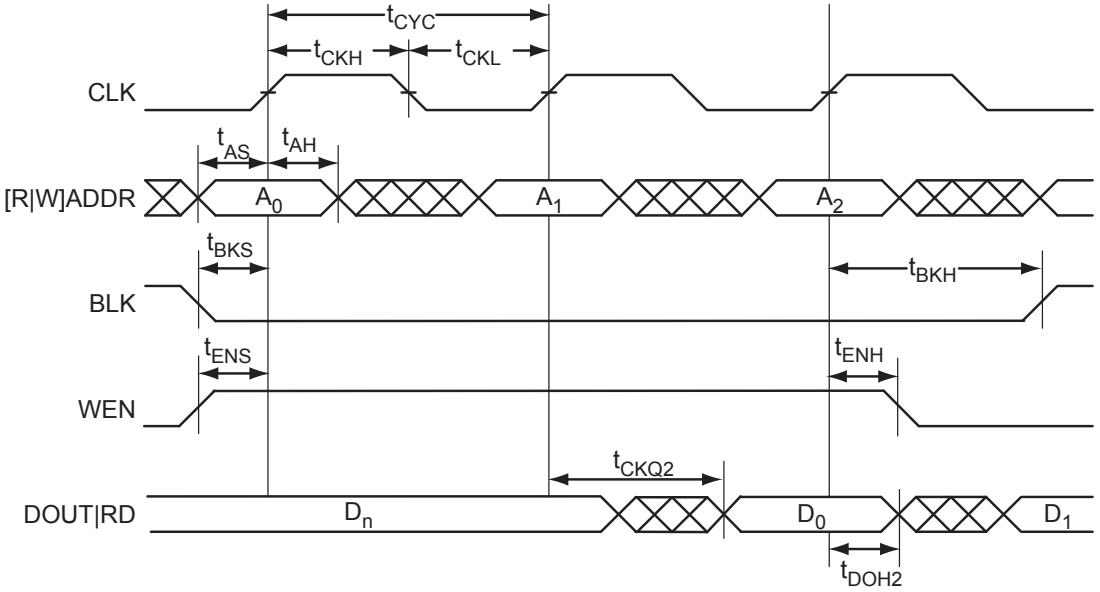


Figure 2-31 • **RAM Read for Pipelined Output Applicable to both RAM4K9 and RAM512x18.**

Analog-to-Digital Converter (ADC)

Unless otherwise noted, ADC direct input performance is specified at 25°C with nominal power supply voltages, with the output measured using the external voltage reference with the internal ADC in 12-bit mode and 500 KHz sampling frequency, after trimming and digital compensation.

***Table 2-95* • ADC Specifications**

Specification	Test Conditions	Min.	Typ.	Max.	Units
Input voltage range (for driving ADC over its full range)			2.56		V
Gain error			±0.4	±0.7	%
	–40ºC to +100ºC		±0.4	±0.7	%
Input referred offset voltage			±1	±2	mV
	–40ºC to +100ºC		±1	±2	
Integral non-linearity (INL)	RMS deviation from BFSL				
	12-bit mode		1.71		LSB
	10-bit mode		0.60	1.00	LSB
	8-bit mode		0.2	0.33	LSB
Differential non-linearity (DNL)	12-bit mode		2.4		LSB
	10-bit mode		0.80	0.94	LSB
	8-bit mode		0.2	0.23	LSB
Signal to noise ratio		62	64		dB
Effective number of bits (ENOB) $ENOB = \frac{SINAD - 1.76\ dB}{6.02\ dB/bit}$ *EQ 10*	–1 dBFS input				
	12-bit mode 10 KHz	9.9	10		Bits
	12-bit mode 100 KHz	9.9	10		Bits
	10-bit mode 10 KHz	9.5	9.6		Bits
	10-bit mode 100 KHz	9.5	9.6		Bits
	8-bit mode 10 KHz	7.8	7.9		Bits
	8-bit mode 100 KHz	7.8	7.9		Bits
Full power bandwidth	At –3 dB; –1 dBFS input	300			KHz
Analog settling time	To 0.1% of final value (with 1 Kohm source impedance and with ADC load)		2		µs
Input capacitance	Switched capacitance (ADC sample capacitor)		12	15	pF
	Cs: Static capacitance (Figure 2-44 on page 2-86)				
	CM[n] input		5	7	pF
	TM[n] input		5	7	pF
	ADC[n] input		5	7	pF
Input resistance	Rin: Series resistance (Figure 2-44)		2		KΩ
	Rsh: Shunt resistance, exclusive of switched capacitance effects (Figure 2-44)	10			MΩ

Note: All 3.3 V supplies are tied together and varied from 3.0 V to 3.6 V. 1.5 V supplies are held constant.

3 – SmartFusion Development Tools

Designing with SmartFusion cSoCs involves three different types of design: FPGA design, embedded design and analog design. These roles can be filled by three different designers, two designers or even a single designer, depending on company structure and project complexity.

Types of Design Tools

Microsemi has developed design tools and flows to meet the needs of these three types of designers so they can work together smoothly on a single project (Figure 3-1).

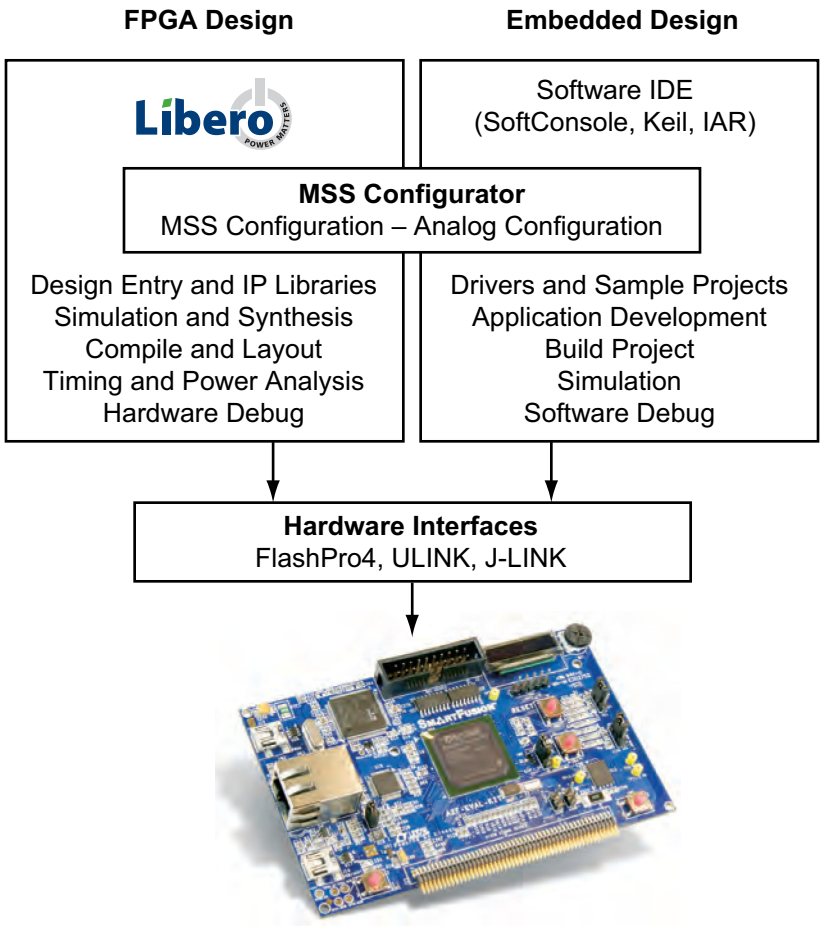


Figure 3-1 • **Three Design Roles**

FPGA Design

Libero System-on-Chip (SoC) software is Microsemi's comprehensive software toolset for designing with all Microsemi FPGAs and cSoCs. Libero SoC includes industry-leading synthesis, simulation and debug tools from Synopsys® and Mentor Graphics®, as well as innovative timing and power optimization and analysis.

- Flash File System (RL-Flash) allows your embedded applications to create, save, read, and modify files in standard storage devices such as ROM, RAM, or FlashROM, using a standard serial peripheral interface (SPI). Many ARM-based microcontrollers have a practical requirement for a standard file system. With RL-FlashFS you can implement new features in embedded applications such as data logging, storing program state during standby modes, or storing firmware upgrades.

Micrium, in addition to µC/OS-III®, offers the following support for SmartFusion cSoC:

- µC/TCP-IP™ is a compact, reliable, and high-performance stack built from the ground up by Micrium and has the quality, scalability, and reliability that translates into a rapid configuration of network options, remarkable ease-of-use, and rapid time-to-market.
- µC/Probe™ is one of the most useful tools in embedded systems design and puts you in the driver's seat, allowing you to take charge of virtually any variable, memory location, and I/O port in your embedded product, while your system is running.

References

PCB Files

A2F500 SmartFusion Development Kit PCB Files

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=130770

A2F200 SmartFusion Development Kit PCB Files

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=130773

Application Notes

SmartFusion cSoC Board Design Guidelines

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129815

Name	Type	Polarity/Bus Size	Description
NCAP		1	Negative capacitor connection. This is the negative terminal of the charge pump. A capacitor, with a 2.2 µF recommended value, is required to connect between PCAP and NCAP. Analog charge pump capacitors are not needed if none of the analog SCB features are used and none of the SDDs are used. In that case it should be left unconnected.
PCAP		1	Positive Capacitor connection. This is the positive terminal of the charge pump. A capacitor, with a 2.2 µF recommended value, is required to connect between PCAP and NCAP. If this pin is not used, it must be left unconnected/floating. In this case, no capacitor is needed. Analog charge pump capacitors are not needed if none of the analog SCB features are used, and none of the SDDs are used.
PTBASE		1	Pass transistor base connection This is the control signal of the voltage regulator. This pin should be connected to the base of an external pass transistor used with the 1.5 V internal voltage regulator and can be floating if not used.
PTEM		1	Pass transistor emitter connection. This is the feedback input of the voltage regulator. This pin should be connected to the emitter of an external pass transistor used with the 1.5 V internal voltage regulator and can be floating if not used.
MSS_RESET_N		Low	Low Reset signal which can be used as an external reset and can also be used as a system level reset under control of the Cortex-M3 processor. MSS_RESET_N is an output asserted low after power-on reset. The direction of MSS_RESET_N changes during the execution of the Microsemi System Boot when chip-level reset is enabled. The Microsemi System Boot reconfigures MSS_RESET_N to become a reset input signal when chip-level reset is enabled. It has an internal pull-up so it can be left floating. In the current software, the MSS_RESET_N is modeled as an external input signal only.
PU_N	In	Low	Push-button is the connection for the external momentary switch used to turn on the 1.5 V voltage regulator and can be floating if not used.

Pin Number	PQ208	
	A2F200	A2F500
63	TM1	TM1
64	CM1	CM1
65	ABPS3	ABPS3
66	ABPS2	ABPS2
67	ADC0	ADC0
68	ADC1	ADC1
69	ADC2	ADC2
70	ADC3	ADC3
71	VAREF0	VAREF0
72	GND33ADC0	GND33ADC0
73	VCC33ADC0	VCC33ADC0
74	GND33ADC0	GND33ADC0
75	VCC15ADC0	VCC15ADC0
76	GND15ADC0	GND15ADC0
77	GND15ADC1	GND15ADC1
78	VCC15ADC1	VCC15ADC1
79	GND33ADC1	GND33ADC1
80	VCC33ADC1	VCC33ADC1
81	GND33ADC1	GND33ADC1
82	VAREF1	VAREF1
83	ADC7	ADC7
84	ADC6	ADC6
85	ADC5	ADC5
86	ADC4	ADC4
87	ABPS6	ABPS6
88	ABPS7	ABPS7
89	CM3	CM3
90	TM3	TM3
91	GNDTM1	GNDTM1
92	TM2	TM2
93	CM2	CM2

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin No.	FG256		
	A2F060 Function	A2F200 Function	A2F500 Function
P10	TM0	TM3	TM3
P11	GNDA	GNDA	GNDA
P12	VCCMAINXTAL	VCCMAINXTAL	VCCMAINXTAL
P13	GNDLPXTAL	GNDLPXTAL	GNDLPXTAL
P14	VDDBAT	VDDBAT	VDDBAT
P15	PTEM	PTEM	PTEM
P16	PTBASE	PTBASE	PTBASE
R1	PCAP	PCAP	PCAP
R2	SDD0	SDD0	SDD0
R3	ADC0	ABPS0	ABPS0
R4	ADC3	TM0	TM0
R5	NC	ABPS2	ABPS2
R6	NC	ADC1	ADC1
R7	NC	VCC33ADC0	VCC33ADC0
R8	VCC15ADC0	VCC15ADC1	VCC15ADC1
R9	ADC10	ADC7	ADC7
R10	ABPS1	ABPS7	ABPS7
R11	NC	ABPS4	ABPS4
R12	MAINXIN	MAINXIN	MAINXIN
R13	MAINXOUT	MAINXOUT	MAINXOUT
R14	LPXIN	LPXIN	LPXIN
R15	LPXOUT	LPXOUT	LPXOUT
R16	VCC33A	VCC33A	VCC33A
T1	NCAP	NCAP	NCAP
T2	ADC1	ABPS1	ABPS1
T3	ADC2	CM0	CM0
T4	NC	GNDTM0	GNDTM0
T5	NC	ADC0	ADC0
T6	NC	VAREF0	VAREF0
T7	NC	GND33ADC0	GND33ADC0
T8	GND15ADC0	GND15ADC1	GND15ADC1

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	FG484	
	A2F200 Function	A2F500 Function
H7	GND	GND
H8	VCC	VCC
H9	GND	GND
H10	VCC	VCC
H11	GND	GND
H12	VCC	VCC
H13	GND	GND
H14	VCC	VCC
H15	GND	GND
H16	VCCFPGAIOB1	VCCFPGAIOB1
H17	IO25NDB1V0	IO29NDB1V0
H18	GCC2/IO25PDB1V0	GCC2/IO29PDB1V0
H19	GND	GND
H20	GCC0/IO26NPB1V0	GCC0/IO35NPB1V0
H21	VCCFPGAIOB1	VCCFPGAIOB1
H22	GCB0/IO27NDB1V0	GCB0/IO34NDB1V0
J1	EMC_DB[6]/GEB0/IO62NDB5V0	EMC_DB[6]/GEB0/IO79NDB5V0
J2	EMC_DB[5]/GEA1/IO61PDB5V0	EMC_DB[5]/GEA1/IO78PDB5V0
J3	EMC_DB[4]/GEA0/IO61NDB5V0	EMC_DB[4]/GEA0/IO78NDB5V0
J4	EMC_DB[3]/GEC2/IO60PPB5V0	EMC_DB[3]/GEC2/IO77PPB5V0
J5	VCCFPGAIOB5	VCCFPGAIOB5
J6	GFA0/IO64NDB5V0	GFA0/IO81NDB5V0
J7	VCCFPGAIOB5	VCCFPGAIOB5
J8	GND	GND
J9	VCC	VCC
J10	GND	GND
J11	VCC	VCC
J12	GND	GND
J13	VCC	VCC
J14	GND	GND
J15	VCC	VCC
J16	GND	GND
J17	NC	IO37PDB1V0
J18	VCCFPGAIOB1	VCCFPGAIOB1

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	FG484	
	A2F200 Function	A2F500 Function
J19	GCA0/IO28NDB1V0	GCA0/IO36NDB1V0 *
J20	GCA1/IO28PDB1V0	GCA1/IO36PDB1V0 *
J21	GCC1/IO26PPB1V0	GCC1/IO35PPB1V0
J22	GCB1/IO27PDB1V0	GCB1/IO34PDB1V0
K1	GND	GND
K2	EMC_DB[0]/GEA2/IO59NDB5V0	EMC_DB[0]/GEA2/IO76NDB5V0
K3	EMC_DB[1]/GEB2/IO59PDB5V0	EMC_DB[1]/GEB2/IO76PDB5V0
K4	NC	IO74PPB5V0
K5	EMC_DB[2]/IO60NPB5V0	EMC_DB[2]/IO77NPB5V0
K6	NC	IO75PDB5V0
K7	GND	GND
K8	VCC	VCC
K9	GND	GND
K10	VCC	VCC
K11	GND	GND
K12	VCC	VCC
K13	GND	GND
K14	VCC	VCC
K15	GND	GND
K16	VCCFPGAIOB1	VCCFPGAIOB1
K17	NC	IO37NDB1V0
K18	GDA1/IO31PDB1V0	GDA1/IO40PDB1V0
K19	GDA0/IO31NDB1V0	GDA0/IO40NDB1V0
K20	GDC1/IO29PDB1V0	GDC1/IO38PDB1V0
K21	GDC0/IO29NDB1V0	GDC0/IO38NDB1V0
K22	GND	GND
L1	NC	IO73PDB5V0
L2	NC	IO73NDB5V0
L3	NC	IO72PPB5V0
L4	GND	GND
L5	NC	IO74NPB5V0
L6	NC	IO75NDB5V0
L7	VCCFPGAIOB5	VCCFPGAIOB5
L8	GND	GND

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Revision	Changes	Page
Revision 5 (continued)	Available values for the Std. speed were added to the timing tables from Table 2-38 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew to Table 2-92 • JTAG 1532 (SAR 29331). One or more values changed for the –1 speed in tables covering 3.3 V LVCMOS, 2.5 V LVCMOS, 1.8 V LVCMOS, 1.5 V LVCMOS, Combinatorial Cell Propagation Delays, and A2F200 Global Resources.	2-31 to 2-76
	Table 2-80 • A2F500 Global Resource is new.	2-60
	Table 2-90 • eNVM Block Timing, Worst Commercial Case Conditions: T_J = 85°C, VCC = 1.425 V was revised (SAR 27585).	2-76
	The programmable analog specifications tables were revised with updated information.	2-78 to 2-87
	Table 4-1 • Supported JTAG Programming Hardware was revised by adding a note to indicate "planned support" for several of the items in the table.	4-7
	The note on JTAGSEL in the "In-System Programming" section was revised to state that SoftConsole selects the appropriate TAP controller using the CTXSELECT JTAG command. When using SoftConsole, the state of JTAGSEL is a "don't care" (SAR 29261).	4-7
	The "CS288" and "FG256" pin tables for A2F060 are new, comparing the A2F060 function with the A2F200 function (SAR 29353).	5-24
	The "Handling When Unused" column was removed from the "FG256" pin table for A2F200 and A2F500 (SAR 29691).	5-42
Revision 4 (September 2010)	Table 2-8 • Power Supplies Configuration was revised. VCCRCOSC was moved to a column of its own with new values. VCCENVM was added to the table. Standby mode for VJTAG and VPP was changed from 0 V to N/A. "Disable" was changed to "Off" in the eNVM column. The column for RCOSC was deleted.	2-10
	The "Power-Down and Sleep Mode Implementation" section was revised to include VCCROSC.	2-11
Revision 3 (September 2010)	The "I/Os and Operating Voltage" section was revised to list "single 3.3 V power supply with on-chip 1.5 V regulator" and "external 1.5 V is allowed" (SAR 27663).	I
	The CS288 package was added to the "Package I/Os: MSS + FPGA I/Os" table (SAR 27101), "Product Ordering Codes" table, and "Temperature Grade Offerings" table (SAR 27044). The number of direct analog inputs for the FG256 package in A2F060 was changed from 8 to 6.	III, VI, VI
	Two notes were added to the "SmartFusion cSoC Family Product Table" indicating limitations for features of the A2F500 device: *Two PLLs are available in CS288 and FG484 (one PLL in FG256).* *[ADCs, DACs, SCBs, comparators, current monitors, and bipolar high voltage monitors are] Available on FG484 only. FG256 and CS288 packages offer the same programmable analog capabilities as A2F200.* Table cells were merged in rows containing the same values for easier reading (SAR 24748).	II
	The security feature option was added to the "Product Ordering Codes" table.	VI